

isc N-Channel MOSFET Transistor

80N08A

• FEATURES

- Drain Current: $I_D = 80A @ T_C = 25^\circ C$
- Drain Source Voltage
: $V_{DSS} = 80V(\text{Min})$
- Static Drain-Source On-Resistance
: $R_{DS(on)} = 11m\Omega (\text{Max})$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

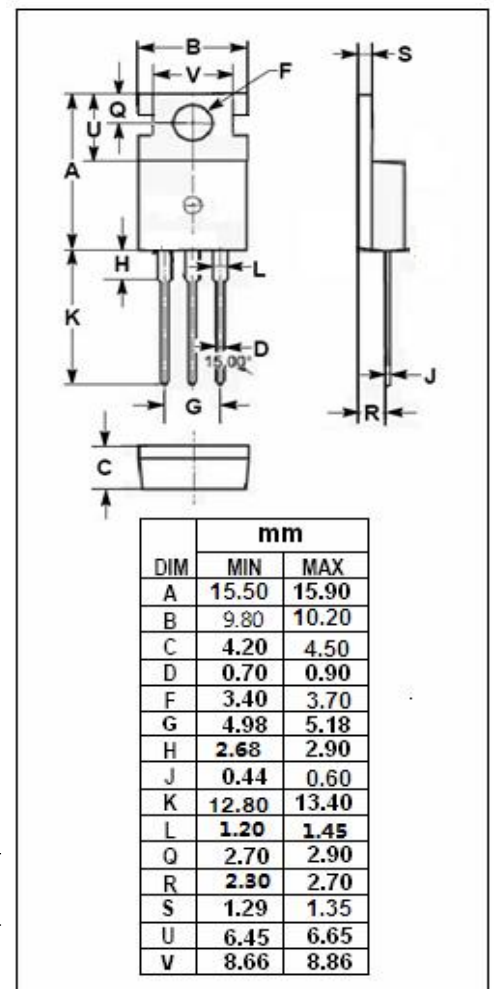
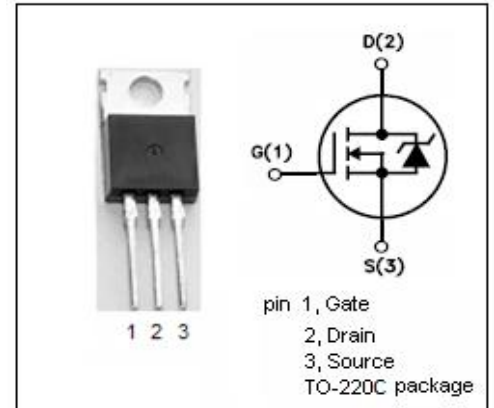
- Power switching applications
- Hard switched and high frequency circuits

• ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	80	V
V_{GS}	Gate-Source Voltage-Continuous	± 20	V
I_D	Drain Current-Continuous	80	A
I_{DM}	Drain Current-Single Plused	380	A
P_D	Total Dissipation @ $T_C = 25^\circ C$	220	W
T_j	Max. Operating Junction Temperature	175	$^\circ C$
T_{stg}	Storage Temperature	-55~175	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.68	$^\circ C/W$



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• ELECTRICAL CHARACTERISTICS

T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =250uA	80			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250uA	2.0		4.0	V
V _{SD}	Diode Forward On-voltage	I _S = 40A; V _{GS} = 0			1.2	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 40A			11	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V; V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80V; V _{GS} = 0			1	uA

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